NSN 5961-01-464-1744

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-464-1744 **Inclosure Material:** Plastic **Overall Length:** 2.9 millimeters **Overall Height:** 1.1 millimeters **Overall Width:** 2.8 millimeters **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 6.0 reverse voltage, instantaneous all semiconductor device diode **Current Rating Per Characteristic:** 30.00 milliamperes source cutoff current preset all semiconductor device diode **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-collector absolute all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 4 printed circuit Shelf Life: N/a **Unit Of Measure:** Demilitarization: No